Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Overall Length:
Between 0.160 inches and 0.260 inches
Terminal Length:
1.100 inches
Overall Diameter:
Between 0.080 inches and 0.120 inches
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Do-41
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
40.0 repetitive peak reverse voltage, peak total value and 48.0 nonrepetitive peak reverse voltage
Current Rating Per Characteristic:
1.00 amperes forward current, average absolute and 25.00 amperes forward current, average preset
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius junction
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A110a0